

# SHINDENGEN

## VX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2188**  
**(F10F50VX2)**

**500V 10A**

### FEATURES

Input capacitance (Ciss) is small.  
Especially, input capacitance at 0 bias is small.  
The static Rds(on) is small.  
The switching time is fast.

### APPLICATION

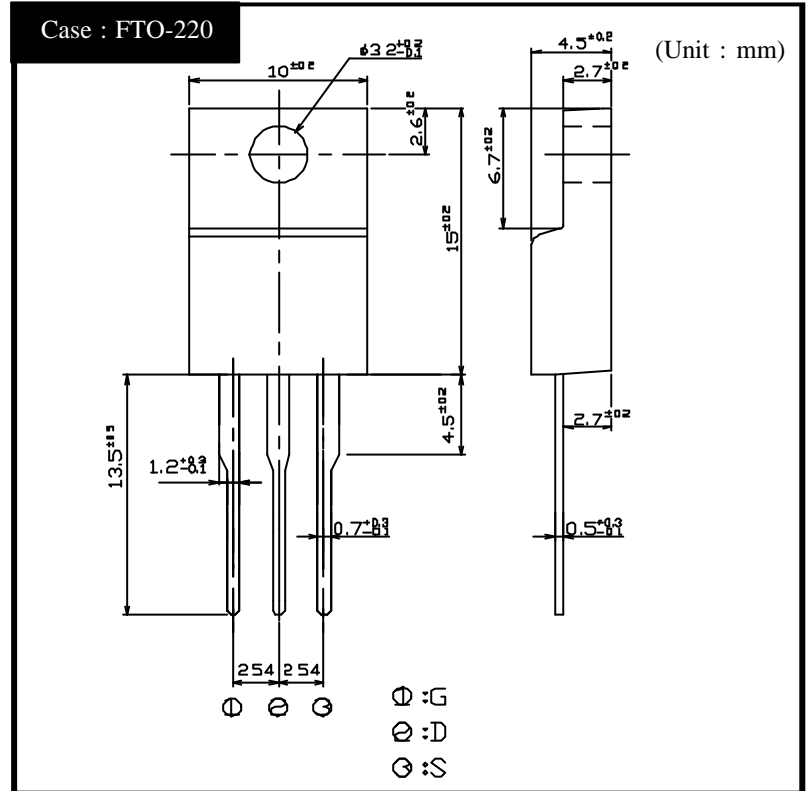
Switching power supply of AC 100V input  
High voltage power supply  
Inverter

### RATINGS

Absolute Maximum Ratings (Tc = 25 )

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T <sub>stg</sub>		-55 ~ 150	
Channel Temperature	T <sub>ch</sub>		150	
Drain-Source Voltage	V <sub>DSS</sub>		500	V
Gate-Source Voltage	V <sub>GSS</sub>		± 30	
Continuous Drain Current (DC )	I <sub>D</sub>		10	A
Continuous Drain Current (Peak)	I <sub>DP</sub>		30	
Continuous Source Current (DC )	I <sub>S</sub>		10	
Total Power Dissipation	P <sub>T</sub>		40	W
Single Pulse Avalanche Current	I <sub>AS</sub>	T <sub>ch</sub> = 25	10	A
Dielectric Strength	V <sub>dis</sub>	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.3N·m )	0.5	N·m

### OUTLINE DIMENSIONS

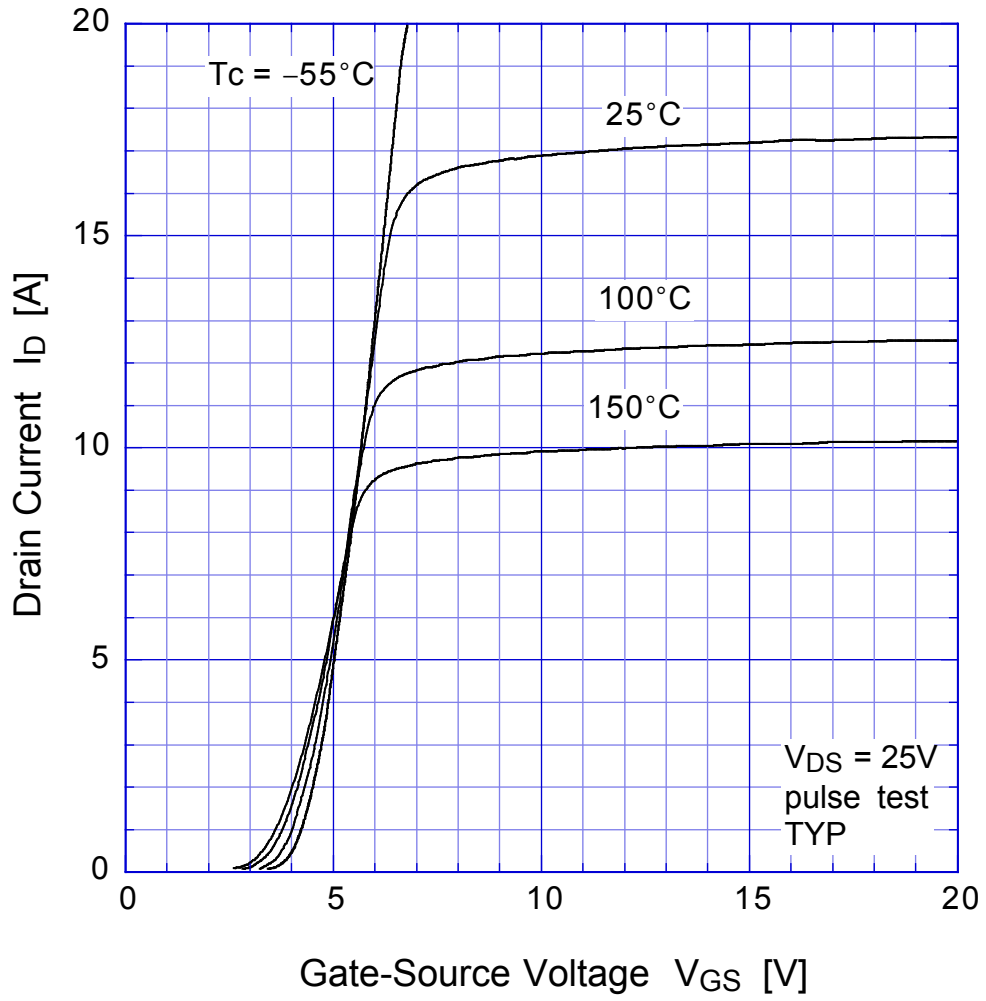


●Electrical Characteristics  $T_c = 25^\circ\text{C}$

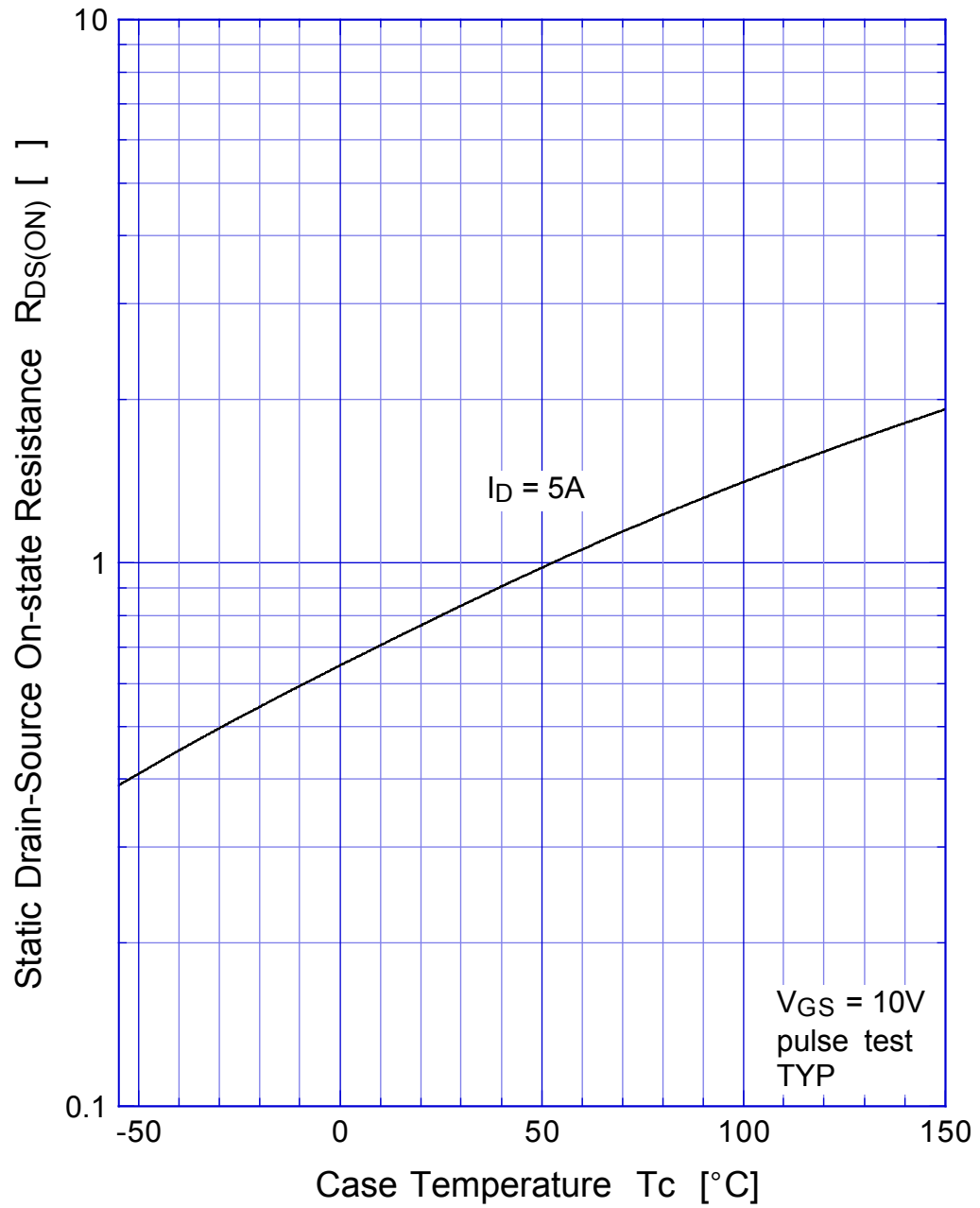
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1\text{mA}, V_{GS} = 0\text{V}$	500			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 500\text{V}, V_{GS} = 0\text{V}$			250	$\mu\text{A}$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$			$\pm 0.1$	
Forward Transconductance	$g_{fs}$	$I_D = 5\text{A}, V_{DS} = 10\text{V}$	2.4	6.3		S
Static Drain-Source On-state Resistance	$R_{DS(ON)}$	$I_D = 5\text{A}, V_{GS} = 10\text{V}$		0.8	1.0	$\Omega$
Gate Threshold Voltage	$V_{TH}$	$I_D = 1\text{mA}, V_{DS} = 10\text{V}$	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	$V_{SD}$	$I_S = 5\text{A}, V_{GS} = 0\text{V}$			1.5	
Thermal Resistance	$\theta_{jc}$	junction to case			3.12	$^\circ\text{C}/\text{W}$
Total Gate Charge	$Q_g$	$V_{DD} = 400\text{V}, V_{GS} = 10\text{V}, I_D = 10\text{A}$		30		nC
Input Capacitance	$C_{iss}$	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$		890		pF
Reverse Transfer Capacitance	$C_{rss}$			70		
Output Capacitance	$C_{oss}$			200		
Turn-On Time	$t_{on}$	$I_D = 5\text{A}, V_{GS} = 10\text{V}, R_L = 30\Omega$		70	110	ns
Turn-Off Time	$t_{off}$	$V_{GS} = 0\text{V}$		140	220	

# 2SK2188

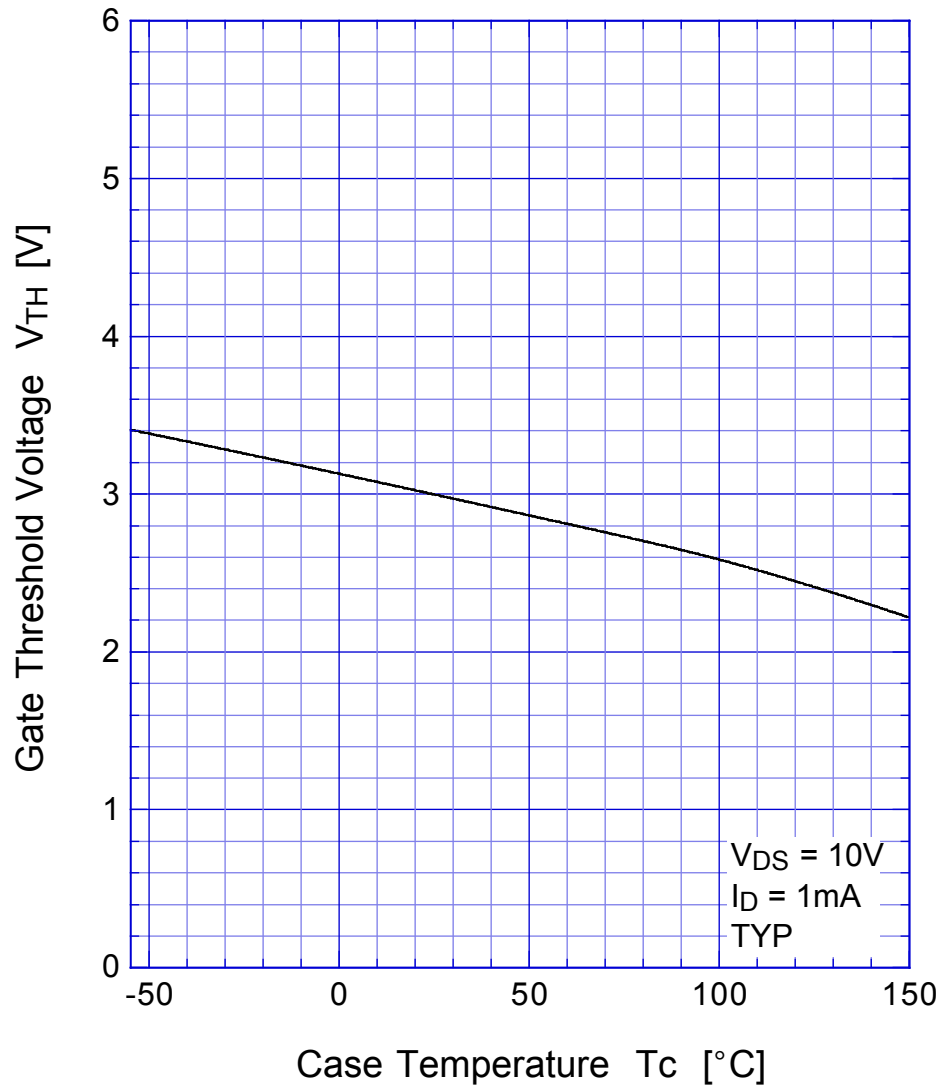
## Transfer Characteristics



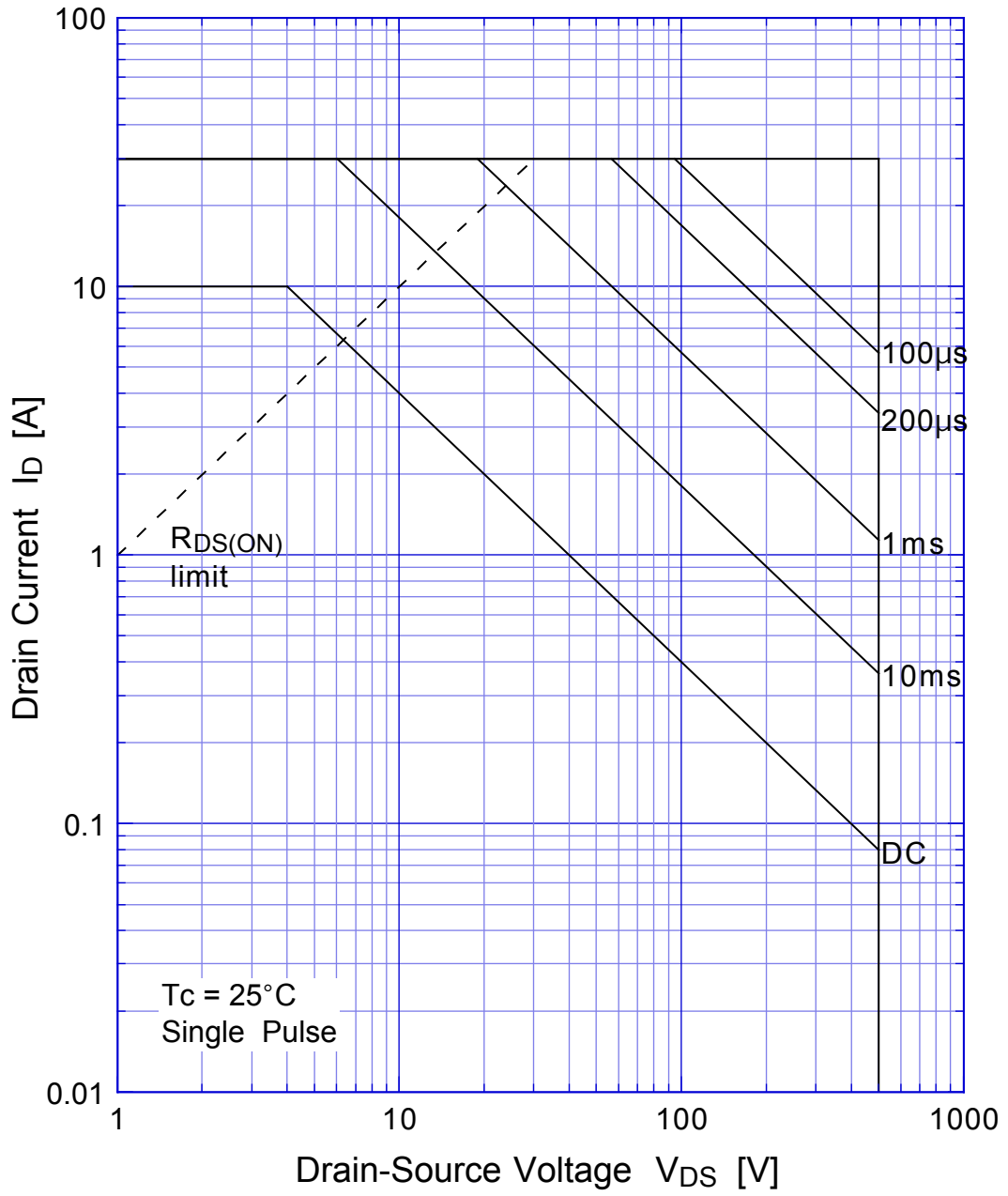
## 2SK2188 Static Drain-Source On-state Resistance



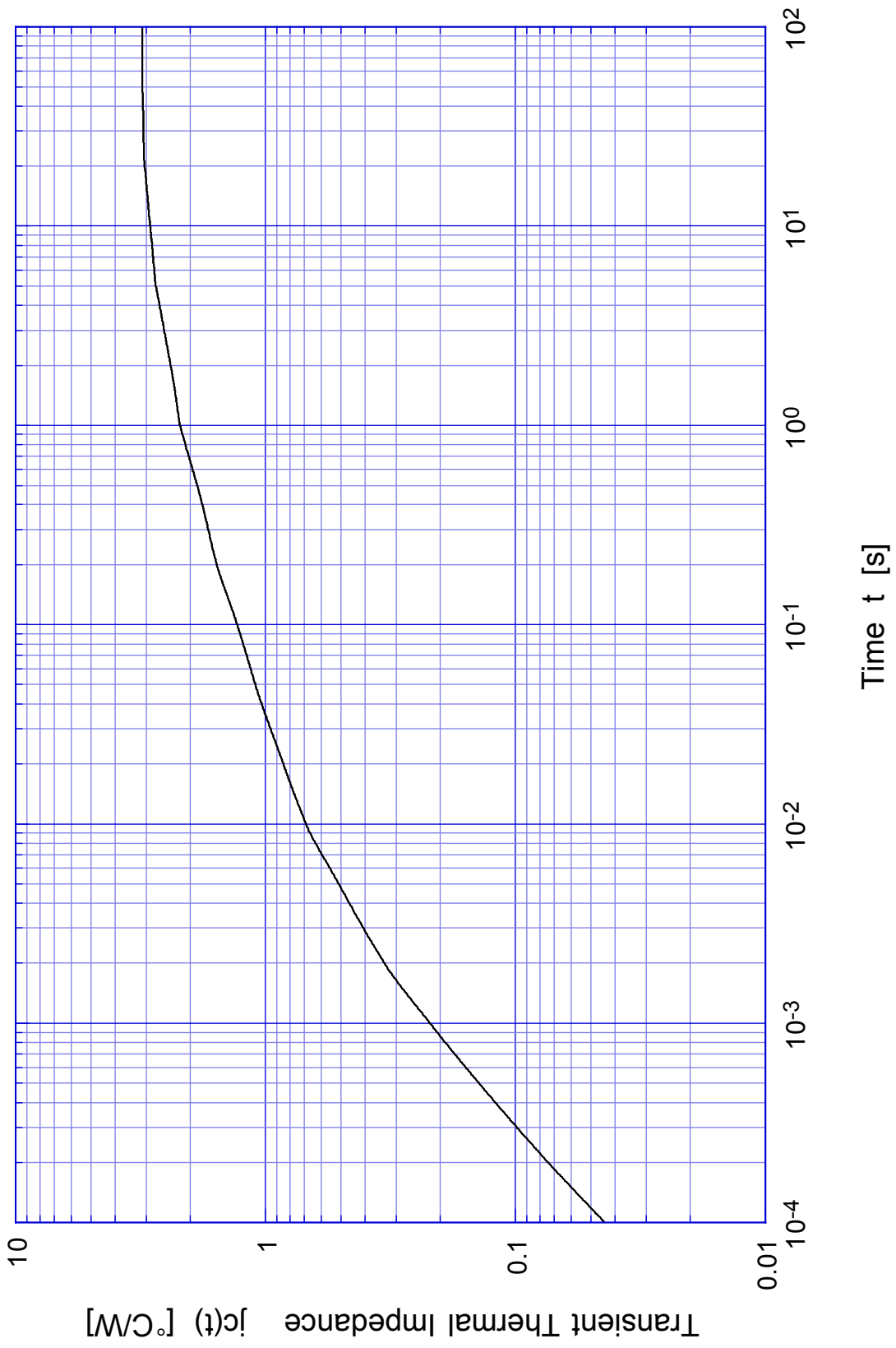
## 2SK2188 Gate Threshold Voltage



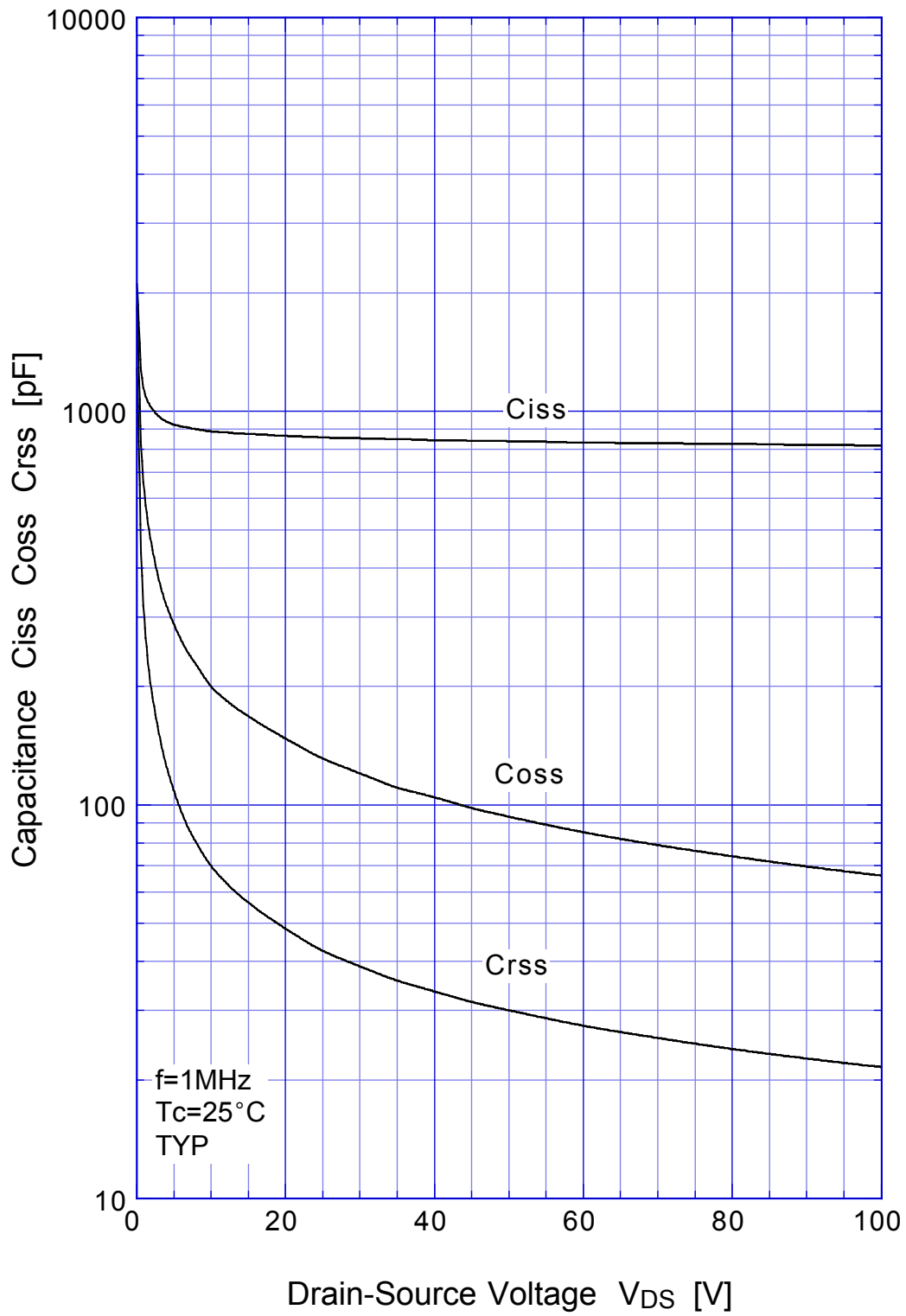
# 2SK2188 Safe Operating Area



# 2SK2188 Transient Thermal Impedance



# 2SK2188 Capacitance



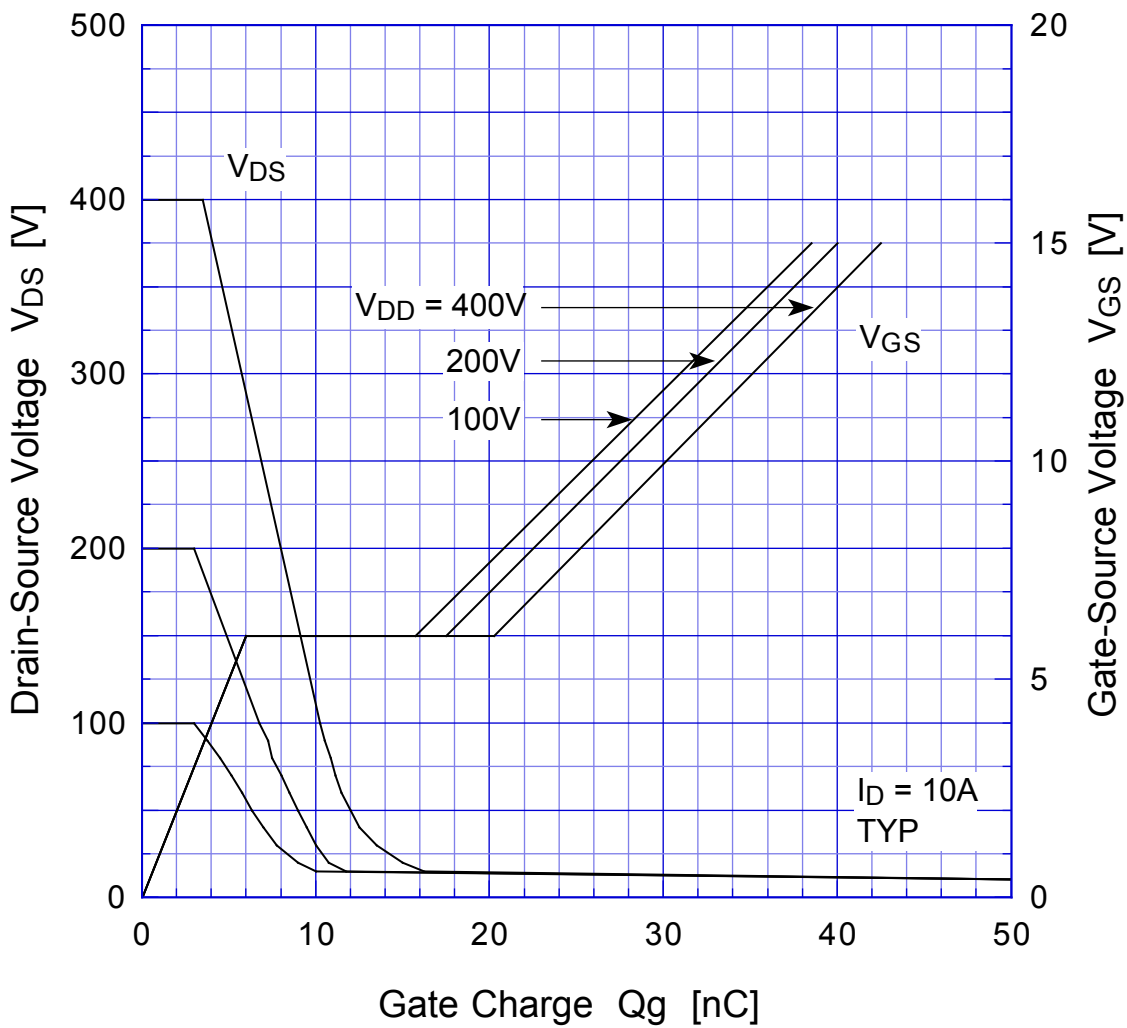


2SK2188

Power Derating



# 2SK2188 Gate Charge Characteristics



**This datasheet has been downloaded from:**

**[www.EEworld.com.cn](http://www.EEworld.com.cn)**

**Free Download**

**Daily Updated Database**

**100% Free Datasheet Search Site**

**100% Free IC Replacement Search Site**

**Convenient Electronic Dictionary**

**Fast Search System**

**[www.EEworld.com.cn](http://www.EEworld.com.cn)**